



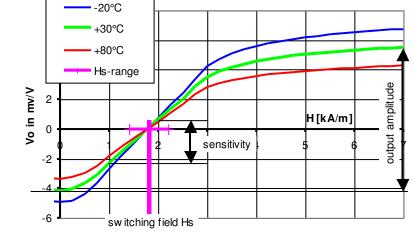
MS32

Switching Sensor

SPECIFICATIONS

- AMR Switching-Sensor
- TDFN Outline 2.5x2.5x0.8 mm³
- Temperature Compensated Switching Point
- Low Power Consumption

The MS32 is a magnetic field sensor which is built in the form of a Wheatstone bridge. Each of its four resistors is made from *Permalloy,* a material that shows the *anisotropic magneto resistance effect.* An unidirectional magnetic field in the surface parallel to the chip (x-y plane) along the y-axis will deliver a field dependent output signal. A **magnetic switching point**, which is almost **independent on temperature** is typically set to Hs=1.85 kA/m. In addition, the characteristic curve is linear over a wide magnetic field range. Thus, the new MS32 simplifies the adaption of the sensor to different mechanical and magnetical environments. The sensor die is packaged in a TDFN package.



APPLICATIONS

- Contactless position detection (presence, open/close)
- Industrial
- Consumer
- Automotive
- Small stroke pneumatic cylinders
- Cover positions of Notebooks and Mobiles
- Doors, windows etc.

MS32 Hy

Figure 1: Characteristic curves for MS32 at different ambient temperatures (-20°C, +30°C, +80°C)

FEATURES

- Sensor based on solid state
 magnetoresistance effect
- Unipolar signal output
- Linear field response
- High sensitivity, low hysteresis
- Temperature compensated switching point
- Low power consumption due to high bridge resistance
- Supply voltage up to 30 V
- Small TDFN package

CHARACTERISTIC VALUES

| Parameter | Condition | Symbol | Min | Тур | Мах | Unit | |
|--------------------------|-----------|----------------------|-----|-------------|------|-----------------|--|
| Mechanical dimensions | | | | | | | |
| Length | | Х | | 2.5 | | mm | |
| Width | | Y | | 2.5 | | mm | |
| Height | | Z | | 0.75 | | mm | |
| Pad size | 7) | | | 0.25 x 0.30 | | mm ² | |
| Operating limits | | | | | | | |
| Max. supply voltage | | V _{CC, MAX} | | | 30 | V | |
| Temp. compensation range | | Тсомр | -25 | | +85 | °C | |
| Operating temperature | | TOP | -45 | | +125 | °C | |
| Storage temperature | | T _{ST} | -45 | | +150 | °C | |

Stress above one or more of the limiting values may cause permanent damage to the device. Exposure to limiting values for extended periods may affect device reliability.

| Parameter | Condition | Symbol | Min | Тур | Max | Unit |
|-------------------------------------|----------------------|------------------|------------------|-------|------|---------------|
| Sensor specification (V | /cc = 5 V, T = 30 °C | C) | | | | |
| Supply voltage | | Vcc | | 5 | 30 | V |
| Resistance | | R _B | 10300 | 11500 | | |
| Offset | | VOFF/VCC | | -4 | -1.5 | mV/V |
| Sensitivity | 1) | S | 2 | 3 | | (mV/V)/(kA/m) |
| Output amplitude | 2) | VMAX | 8 | | | mV/V |
| Hysteresis (@ V ₀ =0) 3) | | Hyst. | | | 0.9 | mV/V |
| Sensor specification (1 | = -25 °C; +85°C; | Conditions A & B | e) ⁶⁾ | | | |
| TC of amplitude | | TCSV | | -0.35 | | %/K |
| TC of bridge resistance | | TCBR | | +0.35 | | %/K |
| Switching field 5) | 4) | Hs | 1.40 | 1.85 | 2.30 | kA/m |

All parameters are measured on wafer level.

1) average gradient in the range 1.0 - 2.0 kA/m

2) difference between output voltage/supply voltage measured at H = 7 kA/m and H = 0 kA/m

3) hysteresis [in kA/m] = hysteresis [in mV/V] /S

4) switching voltage = 0 mV/V

5) switching field = magnetic field at switching voltage

6) values at -25°C can be determined by linear extrapolation from +30°C- and +85°C-values.

7) recommended solder reflow process according to IPC/JEDEC J-STD-020D (Pb-Free Process)

MEASUREMENT CONDITIONS

| Parameter | Symbol | Unit | Condition | | |
|---|----------------|---------|--|--|--|
| A. Set Up Conditions | | | | | |
| ambient temperature | Т | °C | T = 23 +/- 5 °C (unless otherwise noted) | | |
| supply voltage | Vcc | V | V _{CC} = 5 V | | |
| applied magnetic field | H _Y | kA/m | $H_Y = -7 + 7 \text{ kA/m}$; along y-direction; $ H_X < 100 \text{ A/m}$ Pre-magnetization along x-direction with $H_X >= 3 \text{ kA/m}$ | | |
| B. Parameter Definitions (T= -25 °C, +85 °C) see characteristic values 6) | | | | | |
| ambient temperatures | Т | °C | $T_1 = -25$, $T_0 = +30$, $T_2 = +85 \text{ °C}$ | | |
| TC of amplitude | TCSV | %/K | $TCV \bullet \frac{1}{(T_2 \ \mathbf{k}T_1)} \stackrel{\underline{V}_a(T_2)}{\longrightarrow} \frac{\mathbf{k}V_a(T_1)}{V_a(T_1)} \stackrel{\bullet}{\longrightarrow} 00\%$ | | |
| TC of resistance | TCBR | %/K | $TCR \bullet \frac{1}{(T_2 \ \&T_1)} \stackrel{R(T_2) \ \&R(T_1)}{R(T_1)} \stackrel{\text{T00\%}}{R(T_1)}$ | | |
| TC of offset | TCVOFF | μV/(VK) | $TCVoff \bullet \frac{Voff(T_2) \And Voff(T_1)}{(T_2 \And T_1)}$ | | |

BLOCK DIAGRAM

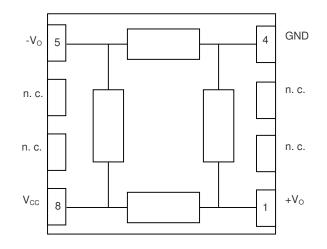


Figure 2: internal and external connections (TDFN, Chip)

SENSOR OUTLINE

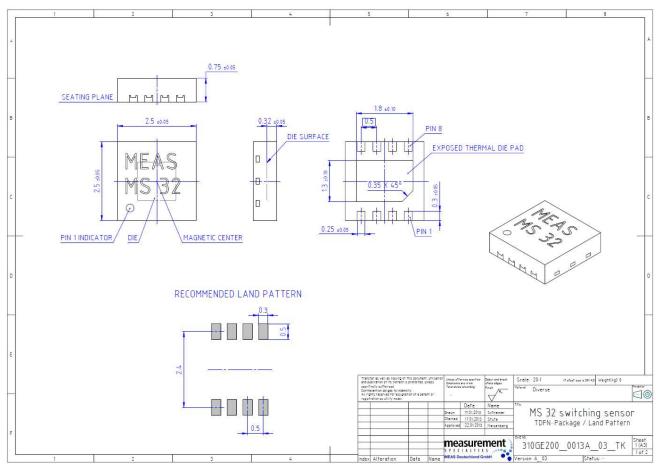


Figure 3: TDFN-package outline and recommended land pattern

Pin assignment

| Pin | Symbol | Function | |
|-----|--------|------------------------|--|
| 1 | +Vo | positive output bridge | |
| 2 | n. c. | not connected | |
| 3 | n. c. | not connected | |
| 4 | GND | ground | |
| 5 | -Vo | negative output bridge | |
| 6 | n. c. | not connected | |
| 7 | n. c. | not connected | |
| 8 | Vcc | supply voltage bridge | |

Note:

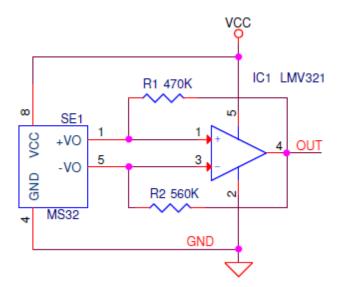
Pin 1 position is marked by a dot on the top side and by the chamfered corner of the bottom plate. The bottom plate is designated to be a heat sink. It has no electrical connection to any pin. The sensitive area is positioned in the center of the package.

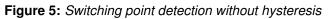
APPLICATION



Figure 4: Typical application geometry of MS32

CIRCUIT EXAMPLES





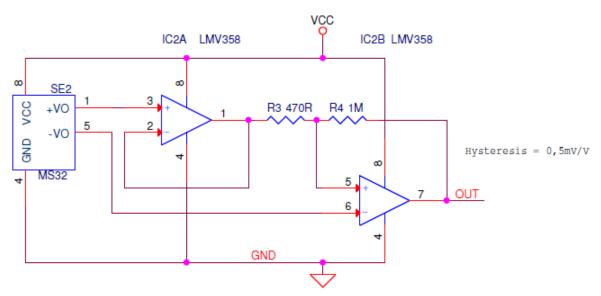


Figure 6: Switching point detection with hysteresis

TAPE AND REEL PACKAGING INFORMATION

| Description | Reel size | Units/reel | Pin 1 orientation | Note |
|-------------|-----------|------------|---------------------------------|------|
| MS32 | 7" | 3,000 | Top-right of sprocket hole side | |

ORDERING CODE

| Device | Package | MOQ | Part number | |
|----------|-----------------|---------|-------------|--|
| MS32 die | Wafer / undiced | 1 wafer | on request | |
| MS32 | TDFN 2.5 x 2.5 | 1 reel | G-MRCO-017 | |

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